### APDS-9950

# Digital Proximity, RGB and Ambient Light Sensor



# **Data Sheet**



### **Description**

The APDS-9950 device provides red, green, blue, and clear (RGBC) light sensing and proximity detection. The devices detect light intensity under a variety of lighting conditions and through a variety of attenuation materials, including dark glass. The proximity detection feature allows a large dynamic range of operation for accurate distance detection, such as in a cell phone, for detecting when the user positions the phone close to their ear. IR LED sink current is factory-trimmed to provide consistent proximity response without requiring customer calibrations. An internal state machine provides the ability to put the device into a low power state in between proximity and RGBC measurements, providing very low average power consumption.

The color-sensing feature is useful in applications such as LED RGB backlight control, solid-state lighting, reflected LED color sampler, or fluorescent light color temperature detection. The integrated IR blocking filter makes this device an excellent ambient light sensor and color temperature monitor sensor.

### **Ordering Information**

Part Number	Packaging	Quantity
APDS-9950	Tape & Reel	2500 per reel

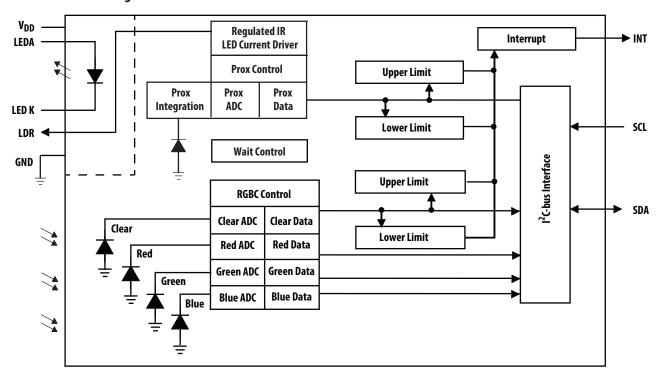
#### **Features**

- RGB and Clear Color Sensing and Proximity Detector and IR LED in an Optical Module
- Color Light Sensing with IR Blocking Filter
  - Programmable Analog Gain and Integration Time
  - Very High Sensitivity Ideally suited for Operation Behind Dark Glass
- Proximity Detection
  - Trimmed for Calibrated 100 mm Detection
  - Ambient Light Rejection
  - Integrated IR LED and LED Driver
- Maskable Light and Proximity Interrupt
  - Programmable Upper and Lower Thresholds with Persistence Filter
- Power Management
  - Low Power 2.5 μA Sleep State
  - 85 μA Wait State with Programmable Wait State Timer from 2.4 ms to > 7 sec
- I<sup>2</sup>C-bus Fast Mode Compatible Interface
  - Data Rates up to 400 kHz
  - Input Voltage Levels Compatible with  $V_{DD}$  or 1.8 V  $V_{BUS}$
  - Dedicated Interrupt Pin
- Small Package L 3.94 × W 2.36 × H 1.35 mm

### **Applications**

- OLED Display Control
- RGB LED Backlight Control
- Ambient Light Color Temperature Sensing
- Cell Phone Touch-screen Disable
- Automatic Speakerphone Enable
- Automatic Menu Pop-up
- Mechanical Switch Replacement
- Industrial Process Control

### **Functional Block Diagram**



### **Description**

The APDS-9950 is a next-generation digital color light sensor device containing four integrating analog-to-digital converters (ADCs) that integrate currents from photodiodes. Multiple photodiode segments for red, green, blue, and clear are geometrically arranged to reduce the reading variance as a function of the incident light angle. Integration of all color sensing channels occurs simultaneously. Upon completion of the conversion cycle, the conversion result is transferred to the corresponding data registers. The transfers are double-buffered to ensure that the integrity of the data is maintained. Communication with the device is accomplished through a fast (up to 400 kHz), two-wire I<sup>2</sup>C serial bus for easy connection to a microcontroller or embedded controller.

The APDS-9950 provides a separate pin for level-style interrupts. When interrupts are enabled and a preset value is exceeded, the interrupt pin is asserted and remains asserted until cleared by the controlling firmware. The interrupt feature simplifies and improves system efficiency by eliminating the need to poll a sensor for a light intensity or proximity value. An interrupt is generated when the value of a clear channel or proximity conversion exceeds either an upper or lower threshold. In addition, a programmable interrupt persistence feature allows the user to determine how many consecutive exceeded thresholds are necessary to trigger an interrupt. Interrupt thresholds and persistence settings are configured independently for both clear and proximity.

Proximity detection is done using a dedicated proximity photodiode centrally located beneath an internal lens, an internal LED, and a driver circuit. The driver circuit requires no external components and is trimmed to provide a calibrated proximity response. Customer calibrations are usually not required.

The number of proximity LED pulses can be programmed from 1 to 255 pulses. Each pulse has a 14 µs period.

This LED current coupled with the programmable number of pulses provides a 2000:1 contiguous dynamic range.

### I/O Pins Configuration

Pin	Name	Туре	Description
1	SDA	I/O	I <sup>2</sup> C serial data I/O terminal - serial data I/O for I <sup>2</sup> C-bus
2	INT	0	Interrupt - open drain (active low)
3	LDR		LED driver input for proximity IR LED, constant current source LED driver
4	LEDK		LED Cathode, connect to LDR pin when using internal LED driver circuit
5	LEDA		LED Anode, connect to V <sub>BATT</sub> on PCB
6	GND		Power supply ground. All voltages are referenced to GND
7	SCL	I	I <sup>2</sup> C serial clock input terminal - clock signal for I <sup>2</sup> C serial data
8	$V_{DD}$		Power supply voltage

### Absolute Maximum Ratings over operating free-air temperature range (unless otherwise noted)\*

Parameter	Symbol	Min	Max	Units	Conditions	
Power supply voltage [1]	$V_{DD}$		3.8	V		
Input voltage range	$V_{IN}$	-0.5	3.8	V		
Output voltage range	V <sub>OUT</sub>	-0.3	3.8	V		
Storage temperature range	T <sub>stg</sub>	-40	85	°C		

<sup>\*</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Note 1. All voltages are with respect to GND.

### **Recommended Operating Conditions**

Parameter	Symbol	Min	Тур	Max	Units	
Operating ambient temperature	T <sub>A</sub>	-30		85	°C	
Power supply voltage	$V_{DD}$	2.5		3.5	V	
Supply voltage accuracy, V <sub>DD</sub> total error including transients		-3		+3	%	
LED supply voltage	V <sub>BATT</sub>	2.5		4.5	V	

### Operating Characteristics, $V_{DD} = 3 \text{ V}$ , $T_A = 25 \,^{\circ}\text{C}$ (unless otherwise noted)

Symbol	Min	Тур	Max	Units	Test Conditions
I <sub>DD</sub>		235	330	μΑ	Active – LDR pulses off
		85			Wait State
		2.5	10		Sleep Mode – No I <sup>2</sup> C activity
V <sub>OL</sub>	0		0.4	V	3 mA sink current
I <sub>LEAK</sub>	-5		5	μΑ	
I <sub>LEAK</sub>	-10		10	μΑ	
V <sub>IH</sub>	1.25		$V_{DD}$	V	
V <sub>IL</sub>			0.54	V	
	V <sub>OL</sub> ILEAK  ILEAK  VIH	V <sub>OL</sub> 0  I <sub>LEAK</sub> -5  I <sub>LEAK</sub> -10  V <sub>IH</sub> 1.25	I <sub>DD</sub> 235 85 2.5  V <sub>OL</sub> 0  I <sub>LEAK</sub> -5  I <sub>LEAK</sub> -10  V <sub>IH</sub> 1.25	I <sub>DD</sub> 235 330  85  2.5 10  V <sub>OL</sub> 0 0.4  I <sub>LEAK</sub> -5 5  I <sub>LEAK</sub> -10 10  V <sub>IH</sub> 1.25 V <sub>DD</sub>	I <sub>DD</sub> 235 330 μA 85 2.5 10 V <sub>OL</sub> 0 0.4 V I <sub>LEAK</sub> -5 5 μA V <sub>IH</sub> 1.25 V <sub>DD</sub> V

# Optical Characteristics, $V_{DD} = 3 \text{ V}$ , $T_A = 25 \,^{\circ}\text{C}$ , AGAIN = $16\times$ , AEN = 1 (unless otherwise noted) [1]

Parameter	Re	ed Chan	nel	Gre	en Cha	nnel	Blu	e Chanı	nel	Cle	ar Chan	nel	Units	Test
	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max		Conditions
Irradiance	0%		15%	10%		42%	60%		95%	14	17.5	21		$\lambda_D = 465 \text{ nm}^{[2]}$
responsitivity	4%		25%	55%		85%	8%		45%	14.96	18.7	22.44	/μW /cm²	$\lambda_D = 525 \text{ nm}^{[3]}$
	75%		110%	0%		14%	3%		24%	16	20	24	/CITI <sup>2</sup>	$\lambda_D = 625 \text{ nm}^{[4]}$

#### Notes:

- 1. The percentage shown represents the ratio of the respective red, green, or blue channel value to the clear channel value.
- 2. The 465 nm input irradiance is supplied by an InGaN light-emitting diode with the following characteristics: dominant wavelength  $\lambda_D =$  465 nm, spectral halfwidth  $\Delta \lambda_{1/2} =$  22 nm.
- 3. The 525 nm input irradiance is supplied by an InGaN light-emitting diode with the following characteristics: dominant wavelength  $\lambda_D = 525$  nm, spectral halfwidth  $\Delta\lambda_{22} = 35$  nm.
- 4. The 625 nm input irradiance is supplied by a AllnGaP light-emitting diode with the following characteristics: dominant wavelength  $\lambda_D = 625$  nm, spectral halfwidth  $\Delta \lambda_{1/2} = 15$  nm.

### RGBC Characteristics, $V_{DD} = 3 \text{ V}$ , $T_A = 25 \,^{\circ}\text{C}$ , $A_{GAIN} = 16 \times$ , AEN = 1 (unless otherwise noted)

Parameter	Min	Тур	Max	Units	<b>Test Conditions</b>
Dark ALS count value		0	5	counts	$E_e = 0$ , $A_{GAIN} = 60 \times$ , $A_{TIME} = 0 \times D6 (100 \text{ ms})$
ADC integration time step size	2.27	2.4	2.56	ms	A <sub>TIME</sub> = 0×FF
ADC number of integration steps	1		256	steps	
Full scale ADC counts per step			1023	counts	
Full scale ADC count value			65535	counts	$A_{TIME} = 0 \times C0 (153.6 \text{ ms})$
Gain scaling, relative to 1× gain	3.6	4	4.4		4×
setting	14.4	16	17.6		16×
	54	60	66		60×

### Proximity Characteristics, $V_{DD} = 3 \text{ V}$ , $T_A = 25 \,^{\circ}\text{C}$ , PEN = 1 (unless otherwise noted)

Parameter	Min	Тур	Max	Units	Test Condition	ons
I <sub>DD</sub> supply current – LDR Pulse On		3		mA		
ADC conversion time step size	2.27	2.4	2.56	ms		
ADC number of integration steps		1		steps		
Full scale ADC counts			1023	counts		
LED pulse count	0		255	pulses		
LED pulse period		14.0		μs		
LED pulse width – LED on time		6.3		μs		
LED drive current		100		mA	$P_{DRIVE} = 0$	I <sub>SINK</sub> sink current
		50			P <sub>DRIVE</sub> = 1	@ 0.6 V, LDR pin
		25			$P_{DRIVE} = 2$	_
		12.5			$P_{DRIVE} = 3$	
Proximity ADC count value, no object		125	250	counts	3 V LED driv = 00, P <sub>GAIN</sub> :	oower supply V <sub>BATT</sub> = ring 8 pulses, P <sub>DRIVE</sub> = 00, open view (no o reflective object nodule.
Proximity ADC count value, 100 mm distance object	350	440	530	counts	83 mm Kod 100 mm dis pulses, P <sub>DRI</sub>	object – 73 mm × ak 90% grey card, tance, LED driving 8 vE = 00, P <sub>GAIN</sub> = 00, no glass) above the

# IR LED Characteristics, $V_{DD}\,{=}\,3$ V, $T_A\,{=}\,25\,^{\circ}C$ (unless otherwise noted)

Parameter	Min	Тур	Max	Units	Test Conditions
Peak Wavelength, λ <sub>P</sub>		850		nm	$I_F = 20 \text{ mA}$
Spectrum Width, Half Power, Δλ		40		nm	I <sub>F</sub> = 20 mA
Optical Rise Time, T <sub>R</sub>		20		ns	I <sub>F</sub> = 100 mA
Optical Fall Time, T <sub>F</sub>		20		ns	I <sub>F</sub> = 100 mA

# Wait Characteristics, $V_{DD} = 3 \text{ V}$ , $T_A = 25 \,^{\circ}\text{C}$ , WEN = 1 (unless otherwise noted)

Parameter	Min	Тур	Max	Units	Test Conditions
Wait Step Size	2.27	2.4	2.56	ms	$W_{TIME} = 0 \times FF$

# AC Electrical Characteristics, $V_{DD}=3$ V, $T_A=25\,\,^{\circ}\text{C}$ (unless otherwise noted) $^*$

Parameter	Symbol	Min.	Max.	Unit
Clock frequency (I <sup>2</sup> C-bus only)	f <sub>SCL</sub>	0	400	kHz
Bus free time between a STOP and START condition	t <sub>BUF</sub>	1.3	-	μs
Hold time (repeated) START condition. After this period, the first clock pulse is generated	t <sub>HDSTA</sub>	0.6	-	μs
Set-up time for a repeated START condition	t <sub>SU;STA</sub>	0.6	-	μs
Set-up time for STOP condition	t <sub>SU;STO</sub>	0.6	_	μs
Data hold time	t <sub>HD;DAT</sub>	0	-	ns
Data set-up time	t <sub>SU;DAT</sub>	100	-	ns
LOW period of the SCL clock	t <sub>LOW</sub>	1.3	_	μs
HIGH period of the SCL clock	t <sub>HIGH</sub>	0.6	-	μs
Clock/data fall time	t <sub>f</sub>	-	300	ns
Clock/data rise time	t <sub>r</sub>	-	300	ns
Input pin capacitance	Ci	-	10	pF

<sup>\*</sup> Specified by design and characterization; not production tested.

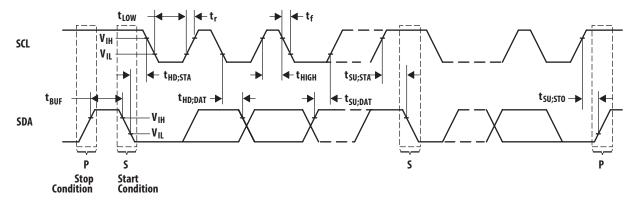


Figure 1. Timing Diagrams

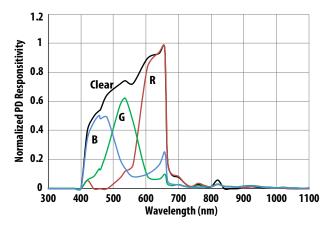


Figure 2. Normalized PD Spectral Response

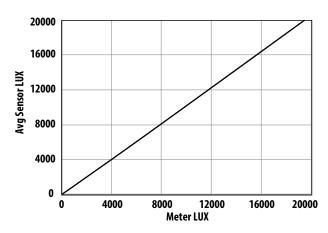


Figure 3. ALS Sensor LUX vs Meter LUX using White Light

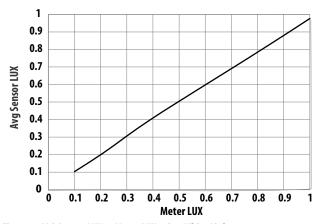


Figure 4. ALS Sensor LUX vs Meter LUX using White Light

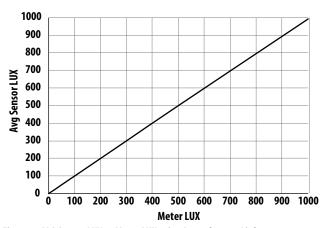


Figure 5. ALS Sensor LUX vs Meter LUX using Incandescent Light

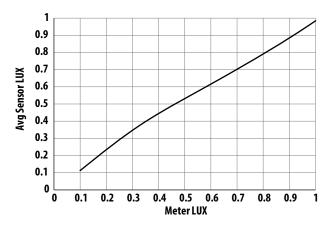


Figure 6. ALS Sensor LUX vs Meter LUX using Incandescent Light

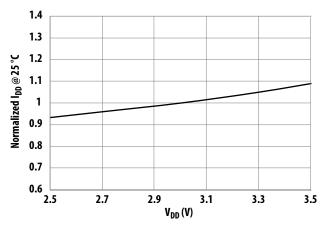


Figure 7. Normalized IDD vs. VDD

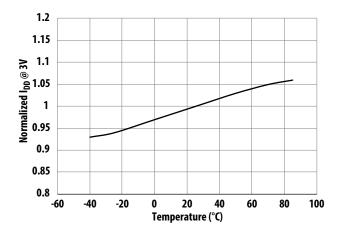


Figure 8. Normalized IDD vs. Temperature

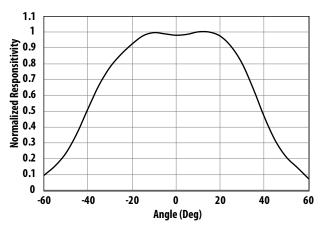


Figure 9. Normalized ALS Response vs. Angular Displacement

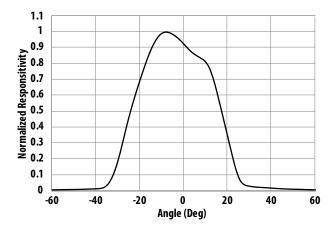


Figure 10. Normalized LED Angular Emitting Profile

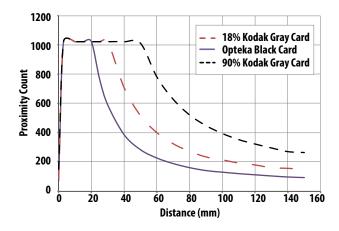


Figure 11a. Proximity Distance Profile (8Pulse, 100 mA,  $1\times$ )

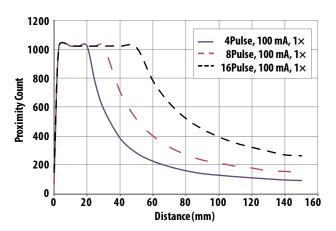


Figure 11b. Proximity Distance Profile (18% Kodak Gray Card)

### **Principles of Operation**

### **System State Machine**

The APDS-9950 provides control of RGBC, proximity detection and power management functionality through an internal state machine. After a power-on-reset, the device is in the sleep mode. As soon as the PON bit is set, the device will move to the start state. It will then continue through the Prox, Wait and RGBC states. If these states are enabled, the device will execute each function. If the PON bit is set to a 0, the state machine will continue until all conversions are completed and then go into a low power sleep mode.

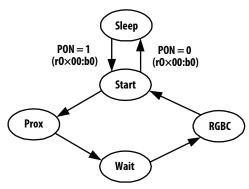


Figure 12. Simplified State Diagram

Note

In this document, the nomenclature uses the bit field name in italics followed by the register number and bit number to allow the user to easily identify the register and bit that controls the function. For example, the power on (PON) is in register 0, bit 0. This is represented as PON (r0:b0).

#### **RGBC Operation**

The RGBC engine contains RGBC gain control (AGAIN) and four integrating analog-to-digital converters (ADC) for the RGBC photodiodes. The RGBC integration time (ATIME) affects both the resolution and the sensitivity of the RGBC reading. Integration of all four channels occurs simultaneously and upon completion of the conversion cycle, the results are transferred to the color data registers. This data is also referred to as channel count. The transfers are double-buffered to ensure that invalid data is not read during the transfer. After the transfer, the device automatically moves to the next state in accordance with the configured state machine.

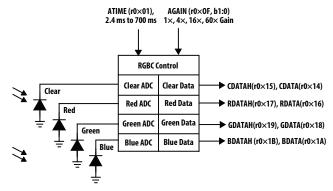


Figure 13. RGBC Operation

The registers for programming the integration and wait times are a 2's complement values. The actual time can be calculated as follows:

 $A_{TIME} = 256 - Integration Time/2.4 ms$ 

Inversely, the time can be calculated from the register value as follows:

Integration Time =  $2.4 \text{ ms}_{\text{ V}} (256 - A_{\text{TIME}})$ 

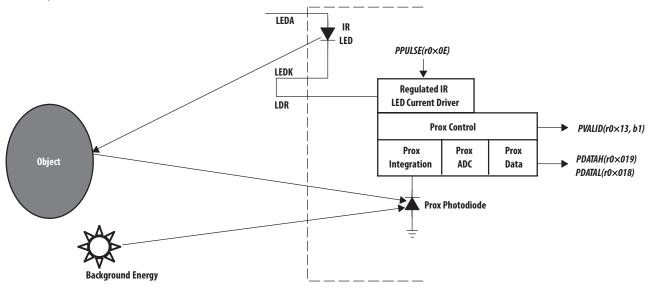
For example, if a 100 ms integration time is needed, the device needs to be programmed to:

$$256 - (100 / 2.4) = 256 - 42 = 214 = 0 \times D6$$

Conversely, the programmed value of 0×C0 would correspond to:

$$(256 - 0 \times C0) \times 2.4 = 64 \times 2.4 = 154 \text{ ms}$$

### **Proximity Detection**



**Figure 14. Proximity Detection** 

Proximity detection measures IR signal energy reflected off a remote object to determine its relative distance. Figure 14 shows light rays emitting from the internal IR LED, reflecting off an object, and being detected by the proximity photodiode. The system response is managed by controlling the number of IR pulses set in P<sub>PULSE</sub> (Proximity Pulse Count Register).

The internal LED current driver provides a regulated current sink on the LDR terminal that eliminates the need for external components. If even higher LED output is needed, currents can be switched using an external P<sub>FET</sub>, gated by the LDR pin. The P<sub>FET</sub> can then sink current from LEDK to ground with an appropriate external current-limiting resistor.

Referring to the Expanded State Diagram (Figure 17), the LED current driver pulses the internal IR LED during the Prox Accum state. Using P<sub>PULSE</sub>, 1 to 255 proximity pulses can be programmed. When deciding on the number of proximity pulses, keep in mind that the signal increases proportionally to PPULSE, while noise increases by the square root of P<sub>PULSE</sub>.

To negate ambient light from the photodiode signal, the background energy is subtracted from the total energy received. Figure 15 illustrates the timing of the LED pulse. The circuitry used to cancel the background energy causes the pulse duty cycle to be asymmetrical as shown. During the LED On time, the reflected signal and the background energy are integrated by the sensor. During the LED Off time, the background energy is subtracted from the integrated value leaving the reflected IR signal to accumulate from pulse to pulse.

After the programmed number of proximity pulses have been generated, the proximity ADC converts and scales the proximity measurement to a 16-bit value, then stores the result in two 8-bit proximity data (PDATAx) registers. The PSAT control (Control Register) can be used to assist with detecting analog saturation at the sensor. When PSAT = 1 the PDATA output registers will show the dark current value (< 5) if saturation is determined to be likely. When PSAT = 0 the PDATA registers will contain the ADC output but if a saturation event happened the results will be inaccurate.

Once the first proximity cycle has completed, the proximity valid (PVALID) bit (Status Register) will be set and remain set until the proximity detection function is disabled (PEN).

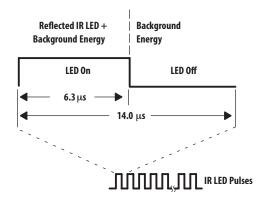


Figure 15. Proximity LED Current Driver Waveform

#### **Interrupts**

The interrupt feature simplifies and improves system efficiency by eliminating the need to poll the sensor for light intensity or proximity values outside of a user-defined range. While the interrupt function is always enabled and it's status is available in the status register (0×13), the output of the interrupt state can be enabled using the proximity interrupt enable (PIEN) or Clear interrupt enable (AIEN) fields in the enable register (0×00).

Four 16-bit interrupt threshold registers allow the user to set limits below and above a desired light level and proximity range. An interrupt can be generated when the Clear data (CDATA) falls outside of the desired light level range, as determined by the values in the Clear interrupt low threshold registers (AILTx) and Clear interrupt high threshold registers (AIHTx). Likewise, an out-of-range proximity interrupt can be generated when the proximity data (PDATA) falls below the proximity interrupt low threshold (PILTx) or exceeds the proximity interrupt high threshold (PIHTx).

Note: The thresholds are evaluated in sequence, first the low threshold, then the high threshold. As a result, if the low threshold is set above the high threshold, the high threshold is ignored and only the low threshold is evaluated.

To further control when an interrupt occurs, the device provides a persistence filter. The persistence filter allows the user to specify the number of consecutive out-of-range Clear or proximity occurrences before an interrupt is generated. The persistence register (0×0C) allows the user to set the Clear persistence (APERS) and the proximity persistence (PPERS) values. See the persistence register for details on the persistence filter values. Once the persistence filter generates an interrupt, it will continue until a special function interrupt clear command is received (see command register).

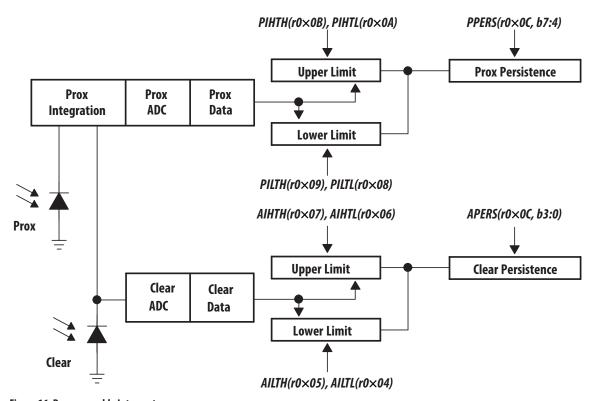


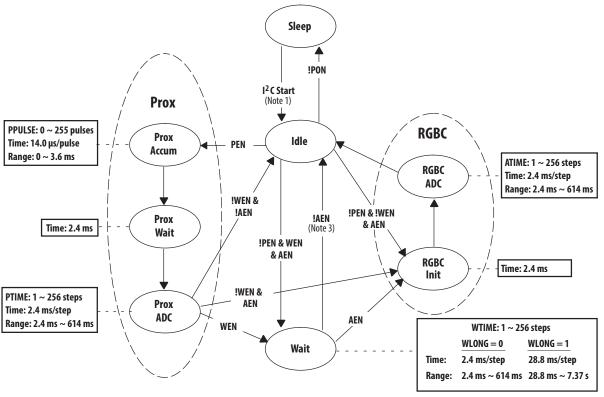
Figure 16. Programmable Interrupt

### **State Diagram**

Figure 17 shows a more detailed flow for the state machine. The device starts in the sleep mode. The PON bit is written to enable the device. A 2.4 ms delay will occur before entering the start state. If the PEN bit is set, the state machine will step through the proximity states of proximity accumulate and then proximity ADC conversion. As soon as the conversion is complete, the state machine will move to the following state.

If the WEN bit is set, the state machine will then cycle through the wait state. If the WLONG bit is set, the wait cycles are extended by 12 over normal operation. When the wait counter terminates, the state machine will step to the RGBC state.

The AEN should always be set, even in proximity-only operation. In this case, a minimum of 1 integration time step should be programmed. The RGBC state machine will continue until it reaches the terminal count, at which point the data will be latched in the RGBC register and the interrupt set, if enabled.



#### Notes:

- 1. There is a 2.4 ms warm-up delay if PON is enabled. If PON is not enabled, the device will return to the Sleep state, as shown.
- 2. PON, PEN, WEN, AEN, and SAI are fields in the Enable register (0x00).
- 3. PON=1, PEN-1, WEN-1, AEN=0 is unsupported and will lead to erroneous proximity readings.

Figure 17. Expanded State Diagram

#### I<sup>2</sup>C Protocol

Interface and control are accomplished through an I<sup>2</sup>C serial compatible interface (standard or fast mode) to a set of registers that provide access to device control functions and output data. The devices support the 7-bit I<sup>2</sup>C addressing protocol.

The device supports a single slave address of  $0\times39$  Hex using 7-bit addressing protocol. (Contact factory for other addressing options.)

A Acknowledge (0)
N Not Acknowledged (1)
P Stop Condition
R Read (1)
S Start Condition
Sr Repeated Start Condition

W Write (0)

Continuation of protocol

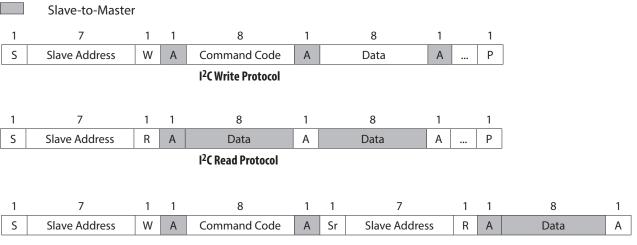
Master-to-Slave

The I<sup>2</sup>C standard provides for three types of bus transaction: read, write, and a combined protocol. During a write operation, the first byte written is a command byte followed by data. In a combined protocol, the first byte written is the command byte followed by reading a series of bytes. If a read command is issued, the register address from the previous command will be used for data access. Likewise, if the MSB of the command is not set, the device will write a series of bytes at the address stored in the last valid command with a register address. The command byte contains either control information or a 5-bit register address. The control commands can also be used to clear interrupts.

The I<sup>2</sup>C bus protocol was developed by Philips (now NXP). For a complete description of the I<sup>2</sup>C protocol, please review the NXP I<sup>2</sup>C design specification at http://www.i2c-bus.org/references/.

8 Data

Α



I<sup>2</sup>C Read Protocol - Combined Format

#### I<sup>2</sup>C Protocol

### **Register Set**

The APDS-9950 is controlled and monitored by data registers and a command register accessed through the serial interface. These registers provide for a variety of control functions and can be read to determine results of the ADC conversions.

Address	Register Name	R/W	Register Function	Reset Value
	COMMAND	W	Specifies register address	0×00
0x00	ENABLE	R/W	Enable of states and interrupts	0×00
0x01	ATIME	R/W	RBGC time	0×FF
0x03	WTIME	R/W	Wait time	0×FF
0x04	AILTL	R/W	Clear interrupt low threshold low byte	0×00
0x05	AILTH	R/W	Clear interrupt low threshold high byte	0×00
0x06	AIHTL	R/W	Clear interrupt high threshold low byte	0×00
0x07	AIHTH	R/W	Clear interrupt high threshold high byte	0×00
0x08	PILTL	R/W	Proximity interrupt low threshold low byte	0×00
0x09	PILTH	R/W	Proximity interrupt low threshold hi byte	0×00
0x0A	PIHTL	R/W	Proximity interrupt hi threshold low byte	0×00
0x0B	PIHTH	R/W	Proximity interrupt hi threshold hi byte	0×00
0x0C	PERS	R/W	Interrupt persistence filters	0×00
0x0D	CONFIG	R/W	Configuration	0×00
0x0E	PPULSE	R/W	Proximity pulse count	0×00
0x0F	CONTROL	R/W	Gain control register	0×00
0x12	ID	R	Device ID	ID
0x13	STATUS	R	Device status	0×00
0x14	CDATAL	R	Clear ADC low data register	0×00
0x15	CDATAH	R	Clear ADC high data register	0×00
0x16	RDATAL	R	Red ADC low data register	0×00
0x17	RDATAH	R	Red ADC high data register	0×00
0x18	GDATAL	R	Green ADC low data register	0×00
0x19	GDATAH	R	Green ADC high data register	0×00
0x1A	BDATAL	R	Blue ADC low data register	0×00
0x1B	BDATAH	R	Blue ADC high data register	0×00
0x1C	PDATAL	R	Proximity ADC low data register	0×00
0x1D	PDATAH	R	Proximity ADC high data register	0×00

The mechanics of accessing a specific register depends on the specific protocol used. See the section on I<sup>2</sup>C protocols on the previous pages. In general, the COMMAND register is written first to specify the specific control/status register for following read/write operations.

### **Command Register**

The command registers specifies the address of the target register for future write and read operations.

	7	6	5	4	3	2	1	0	
COMMAND	COMMAND	TY	PE.			ADD			

Field	Bits	Description	
COMMAND	7	Select Com	mand Register. Must write as 1 when addressing COMMAND register.
TYPE	6:5	Selects type	e of transaction to follow in subsequent data transfers:
		Field Value	Integration Time
		00	Repeated byte protocol transaction
		01	Auto-Increment protocol transaction
		10	Reserved — Do not use
		11	Special function – See description below
			ol will repeatedly read the same register with each data access. col will provide auto-increment function to read successive bytes.
ADD	4:0	specifies a s	d/special function field. Depending on the transaction type, see above, this field either special function command or selects the specific control-status-register for following write sactions. The field values listed below apply only to special function commands:
		Field Value	Read Value
		00000	Normal — no action
		00101	Proximity interrupt clear
		00110	Clear interrupt clear
		00111	Proximity and Clear interrupt clear
		other	Reserved – Do not write
		Clear / Prox is self-cleari	imity Interrupt Clear. Clears any pending Clear / Proximity interrupt. This special function ng.

### Enable Register (0×00)

The ENABLE register is used primarily to power the APDS-9950 device on and off, and enable functions and interrupts.

	7	6	5	4	3	2	1	0	Address
ENABLE	Reserved	Reserved	PIEN	AIEN	WEN	PEN	AEN	PON	0×00

Field	Bits	Description
Reserved	7:6	Reserved. Write as 0.
PIEN	5	Proximity Interrupt Enable. When asserted, permits proximity interrupts to be generated.
AIEN	4	Ambient Light Sensing (ALS) Interrupt Enable. When asserted, permits ALS interrupts to be generated.
WEN [1][2]	3	Wait Enable. This bit activates the wait feature. Writing a 1 activates the wait timer. Writing a 0 disables the wait timer.
PEN [1][2]	2	Proximity Enable. This bit activates the proximity function. Writing a 1 enables proximity. Writing a 0 disables proximity.
AEN [1][2]	1	RGBC Enable. This bit activates the RGBC function. Writing a 1 enables RGBC. Writing a 0 disables RGBC.
PON	0	Power ON. This bit activates the internal oscillator to permit the timers and ADC channels to operate. Writing a 1 activates the oscillator. Writing a 0 disables the oscillator. During reads and writes over the I <sup>2</sup> C interface, this bit is temporarily overridden and the oscillator is enabled, independent of the state of the PON.

#### Notes:

- 1 The PON bit must be set = 1 for these functions to operate.
- 2. WEN = 1, PEN = 1, AEN = 0 is unsupported and will lead to erroneous proximity readings.

### *RGBC Time Register (0×01)*

The RGBC timing register controls the internal integration time of the RGBC clear and IR channel in the ADCs in 2.4 ms increments. Upon power up, the RGBC time register is set to 0xFF.

Field	Bits				
ATIME	7:0	VALUE	INTEG_CYCLES	TIME	MAX COUNT
		0xFF	1	2.4 ms	1024
		0xF6	10	24 ms	10240
		0xD6	42	101 ms	43008
		0xAD	64	154 ms	65535
		0x00	256	614 ms	65535

#### *Wait Time Register (0×03)*

Wait time is set 2.4 ms increments unless the WLONG bit is asserted in which case the wait times are  $12 \times 100$  longer. WTIME is programmed as a 2's complement number. Upon power up, the Wait time register is set to  $0 \times 100$  FF.

Field	Bits		Des	cription	
WTIME	7:0	REGISTER VALUE	WAIT TIME	TIME (WLONG = 0)	TIME (WLONG = 1)
		0xFF	1	2.4 ms	0.029 sec
		0xAB	85	204 ms	2.45 sec
		0x00	256	614 ms	7.4 sec

Note: The Proximity Wait Time Register should be configured before PEN and/or AEN is/are asserted.

### Clear Interrupt Threshold Registers ( $0 \times 04 - 0 \times 07$ )

The Clear interrupt threshold registers provide the values to be used as the high and low trigger points for the comparison function for interrupt generation. If the value generated by the clear channel crosses below the lower threshold specified, or above the higher threshold, an interrupt is asserted on the interrupt pin.

Register	Address	Bits	Description
AILTL	0×04	7:0	Clear channel low threshold lower byte
AILTH	0×05	7:0	Clear channel low threshold upper byte
AIHTL	0×06	7:0	Clear channel high threshold lower byte
AIHTH	0×07	7:0	Clear channel high threshold upper byte

### Proximity Interrupt Threshold Registers $(0 \times 08 - 0 \times 0B)$

The proximity interrupt threshold registers provide the values to be used as the high and low trigger points for the comparison function for interrupt generation. If the value generated by proximity channel crosses below the lower threshold specified, or above the higher threshold, an interrupt is asserted on the interrupt pin.

Register	Address	Bits	Description
PILTL	0x08	7:0	Proximity ADC channel low threshold lower byte
PILTH	0x09	7:0	Proximity ADC channel low threshold upper byte
PIHTL	0x0A	7:0	Proximity ADC channel high threshold lower byte
PIHTH	0x0B	7:0	Proximity ADC channel high threshold upper byte

### Persistence Register (0×0C)

The persistence register controls the filtering interrupt capabilities of the device. Configurable filtering is provided to allow interrupts to be generated after each ADC integration cycle or if the ADC integration has produced a result that is outside of the values specified by threshold register for some specified amount of time. Separate filtering is provided for proximity and the clear channel.

	7	6	5	4	3	2	1	0	
PERS		PPE	ERS			API	ERS		0×0C

Field	Bits	Description					
PPERS	7:4	Proximity Ir processor.	Proximity Interrupt persistence. Controls rate of proximity interrupt to the host processor.				
		Field Value	Meaning	Interrupt Persistence Function			
		0000	Every	Every proximity cycle generates an interrupt			
		0001	1	1 consecutive proximity values out of range			
		0010	2	2 consecutive proximity values out of range			
		•••					
		1111	15	15 consecutive proximity values out of range			
APERS	3:0	Clear Interr	upt persist	ence. Controls rate of Clear interrupt to the host processor.			
		Field Value	Meaning	Interrupt Persistence Function			
		0000	Every	Every RGBC cycle generates an interrupt			
		0001	1	1 consecutive clear channel values out of range			
		0010	2	2 consecutive clear channel values out of range			
		0011	3	3 consecutive clear channel values out of range			
		0100	5	5 consecutive clear channel values out of range			
		0101	10	10 consecutive clear channel values out of range			
		0110	15	15 consecutive clear channel values out of range			
		0111	20	20 consecutive clear channel values out of range			
		1000	25	25 consecutive clear channel values out of range			
		1001	30	30 consecutive clear channel values out of range			
		1010	35	35 consecutive clear channel values out of range			
		1011	40	40 consecutive clear channel values out of range			
		1100	45	45 consecutive clear channel values out of range			
		1101	50	50 consecutive clear channel values out of range			
		1110	55	55 consecutive clear channel values out of range			
		1111	60	60 consecutive clear channel values out of range			

### Configuration Register (0×0D)

The configuration register sets the wait long time.

	7	6	5	4	3	2	1	0	
CONFIG			Rese	rved			WLONG	Reserved	0×0D

Field	Bits	Description
Reserved	7:2	Reserved. Write as 0.
WLONG	1	Wait Long. When asserted, the wait cycles are increased by a factor 12x from that programmed in the WTIME register.
Reserved	0	Reserved. Write as 0.

### *Proximity Pulse Count Register (0×0E)*

The proximity pulse count register sets the number of proximity pulses that will be transmitted.

	7	6	5	4	3	2	1	0	
PPULSE				PPU	JLSE				0×0E
Field	Bits		Descript	ion					
PPULSE	7:0		Proximity Pulse Count. Specifies the number of proximity pulses to be generated.						

### Control Register (0×0F)

The Gain register provides eight bits of miscellaneous control to the analog block. These bits typically control functions such as gain settings and/or diode selection.

_	7	6	5	4	3	2	1	0	_	
CONTROL	PDRI	VE	PDIO	DE	PG	SAIN	AC	SAIN	0×0F	
Field	Bits		Descriptio	n				-		
PDRIVE	7:6		LED Drive Strength							
			Field Valu	e	LED Strength					
			00		100 mA					
			01		50 mA					
			10		25 mA					
			11		12.5 mA					
PDIODE	5:4		Proximity	Diode Selec	t					
			Field Valu	e	LED Strength					
			00		Reserved					
			01		Reserved					
					Proximity use	s the IR Diode				
			11		Reserved					
PGAIN	3:2	3:2		Proximity Gain Control						
			Field Valu	e	LED Strength					
			00		1× Gain					
			01		Reserved					
			10		Reserved					
			11		Reserved					
AGAIN	1:0		RGBC Gain	Control						
			Field Valu	e	RGBC Gain Valu	ıe				
			00		1× Gain					
			01		4× Gain					
			10		16× Gain					
			11		60× Gain					

#### ID Register (0 $\times$ 12)

The ID register provides the value for the part number. The ID is a read-only register.

	/	6	5	4	3	2	1	0	
ID [				ı	D				0×12
Field	Bits		Descript	tion					
ID	7:0		Part nu	mber identifi	cation				_
			0×69 =	APDS-9950					

#### Status Register ( $0 \times 13$ )

The Status Register provides the internal status of the device. This register is read-only.

asserted

STATUS	Reserved	Reserved	PINT	AINT	Reserved	Reserved	PVALID	AVALID	0×13
Field	Bits	5	Descript	ion					
Reserved	7:6		Reserve	Reserved.					
PINT	5		Proximi	Proximity Interrupt.					
AINT	4		Clear In	Clear Interrupt.					
Reserved	3:2		Reserve	Reserved.					
PVALID	1		Proximi	Proximity Valid. Indicates that a proximity cycle has completed since PEN was					was

RGBC Valid. Indicates that a RGBC cycle has completed since AEN was asserted

#### RGBC DATA Register ( $0 \times 14 - 0 \times 1B$ )

0

**AVALID** 

Clear, red, green, and blue data is stored as 16-bit values. To ensure the data is read correctly, a two-byte read I<sup>2</sup>C transaction should be used with a read word protocol bit set in the command register. With this operation, when the lower byte register is read, the upper eight bits are stored into a shadow register, which is read by a subsequent read to the upper byte. The upper register will read the correct value even if additional ADC integration cycles end between the reading of the lower and upper registers.

Register	Address	Bits	Description
CDATAL	0×14	7:0	Clear data low byte
CDATAH	0×15	7:0	Clear data high byte
RDATAL	0×16	7:0	Red data low byte
RDATAH	0×17	7:0	Red data high byte
GDATAL	0×18	7:0	Green data low byte
GDATAH	0×19	7:0	Green data high byte
BDATAL	0×1A	7:0	Blue data low byte
BDATAH	0×1B	7:0	Blue data high byte

#### *Proximity DATA Register* $(0 \times 1C - 0 \times 1D)$

Proximity data is stored as a 16-bit value. To ensure the data is read correctly, a two byte read I<sup>2</sup>C transaction should be utilized with a read word protocol bit set in the command register. With this operation, when the lower byte register is read, the upper eight bits are stored into a shadow register, which is read by a subsequent read to the upper byte. The upper register will read the correct value even if additional ADC integration cycles end between the reading of the lower and upper registers.

Register	Address	Bits	Description
PDATAL	0×1C	7:0	Proximity data low byte
PDATAH	0×1D	7:0	Proximity data high byte

### **Application Information Hardware**

In a proximity sensing system, the included IR LED can be pulsed by the APDS-9950 with more than  $100\,\text{mA}$  of rapidly switching current, therefore, a few design considerations must be kept in mind to get the best performance. The key goal is to reduce the power supply noise coupled back into the device during the LED pulses. If  $V_{BATT}$  does not exceed the maximum specified LDR pin voltage (including when the battery is being recharged), LEDA can be directly tied to  $V_{BATT}$  for best proximity performance.

In many systems, there is a quiet analog supply and a noisy digital supply. By connecting the quiet supply to the VDD pin and the noisy supply to the LED, the key goal can be meet. Place a 1  $\mu\text{F}$  low-ESR decoupling capacitor as close as possible to the VDD pin and another at the LED anode, and a 22  $\mu\text{F}$  capacitor at the output of the LED voltage regulator to supply the 100 mA current surge.

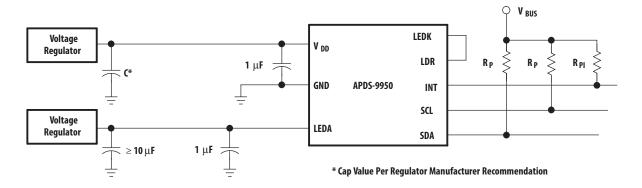


Figure 18a. Circuit Implementation using Separate Power Supplies

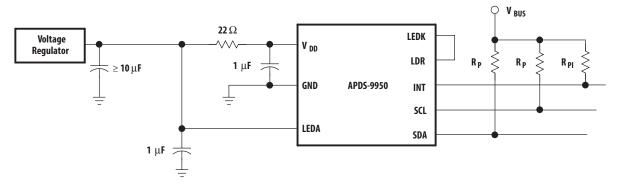


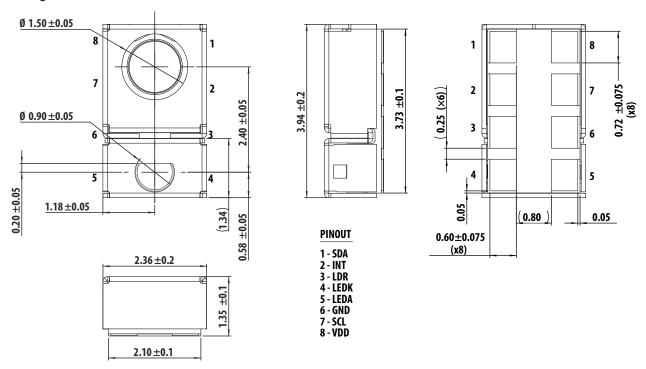
Figure 18b. Circuit Implementation using Single Power Supply

If operating from a single supply, use a 22  $\Omega$  resistor in series with the V<sub>DD</sub> supply line and a 1  $\mu$ F low ESR capacitor to filter any power supply noise. The previous capacitor placement considerations apply.

 $V_{BUS}$  in the above figures refers to the  $I^2C$ -bus voltage which is either  $V_{DD}$  or 1.8 V. Be sure to apply the specified  $I^2C$ -bus voltage shown in the Available Options table for the specific device being used.

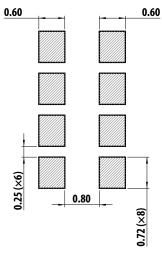
The I<sup>2</sup>C signals and the Interrupt are open-drain outputs and require pull–up resistors. The pull-up resistor (RP) value is a function of the I<sup>2</sup>C-bus speed, the I<sup>2</sup>C-bus voltage, and the capacitive load. A 10 k $\Omega$  pull-up resistor (RPI) can be used for the interrupt line.

# **Package Outline Dimensions**



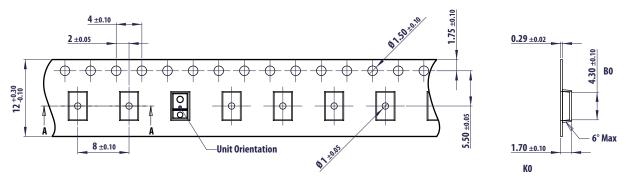
# **PCB Pad Layout**

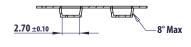
Suggested PCB pad layout guidelines for the Dual Flat No-Lead surface mount package are shown below.



Note: All linear dimensions are in mm.

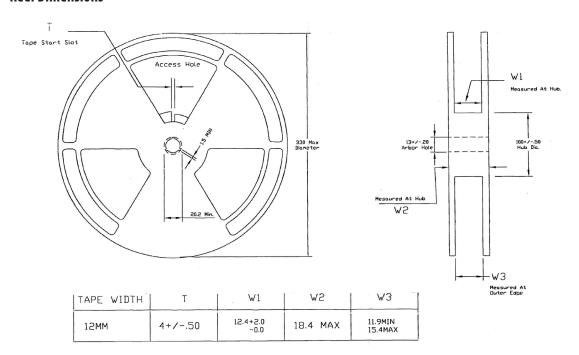
# **Tape Dimensions**





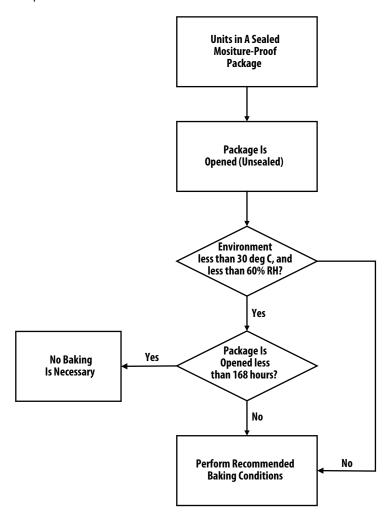
Note: All linear dimensions are in mm.

### **Reel Dimensions**



### **Moisture Proof Packaging**

All APDS-9950 options are shipped in moisture proof package. Once opened, moisture absorption begins. This part is compliant to JEDEC MSL 3.



### **Baking Conditions**

Package	Temperature	Time
In Reel	60 °C	48 hours
In Bulk	100 °C	4 hours

If the parts are not stored in dry conditions, they must be baked before reflow to prevent damage to the parts.

Baking should only be done once.

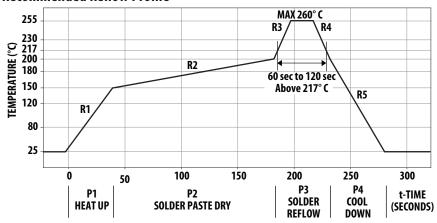
### **Recommended Storage Conditions**

Storage Temperature	10 °C to 30 °C
Relative Humidity	below 60% RH

### Time from unsealing to soldering

After removal from the bag, the parts should be soldered within 168 hours if stored at the recommended storage conditions. If times longer than 168 hours are needed, the parts must be stored in a dry box.

#### **Recommended Reflow Profile**



			Maximum $\Delta T/\Delta$ time
Process Zone	Symbol	$\Delta T$	or Duration
Heat Up	P1, R1	25 °C to 150 °C	3 °C/s
Solder Paste Dry	P2, R2	150 °C to 200 °C	100 s to 180 s
Solder Reflow	P3, R3	200 °C to 260 °C	3 °C/s
Solder Rellow	P3, R4	260 °C to 200 °C	-6 °C/s
Cool Down	P4, R5	200 °C to 25 °C	-6 °C/s
Time maintained above liqu	idus point , 217 °C	> 217 °C	60 s to 120 s
Peak Temperature		260 °C	-
Time within 5 °C of actual Pe	eak Temperature	> 255 °C	20 s to 40 s
Time 25 °C to Peak Tempera	ture	25 °C to 260 °C	8 mins

The reflow profile is a straight-line representation of a nominal temperature profile for a convective reflow solder process. The temperature profile is divided into four process zones, each with different  $\Delta T/\Delta t$ ime temperature change rates or duration. The  $\Delta T/\Delta t$ ime rates or duration are detailed in the above table. The temperatures are measured at the component to printed circuit board connections.

In process zone P1, the PC board and component pins are heated to a temperature of 150 °C to activate the flux in the solder paste. The temperature ramp up rate, R1, is limited to 3 °C per second to allow for even heating of both the PC board and component pins.

Process zone P2 should be of sufficient time duration (100 to 180 seconds) to dry the solder paste. The temperature is raised to a level just below the liquidus point of the solder.

Process zone P3 is the solder reflow zone. In zone P3, the temperature is quickly raised above the liquidus point

of solder to 260 °C (500 °F) for optimum results. The dwell time above the liquidus point of solder should be between 60 and 120 seconds. This is to assure proper coalescing of the solder paste into liquid solder and the formation of good solder connections. Beyond the recommended dwell time the intermetallic growth within the solder connections becomes excessive, resulting in the formation of weak and unreliable connections. The temperature is then rapidly reduced to a point below the solidus temperature of the solder to allow the solder within the connections to freeze solid.

Process zone P4 is the cool down after solder freeze. The cool down rate, R5, from the liquidus point of the solder to  $25\,^{\circ}\text{C}$  (77 °F) should not exceed 6 °C per second maximum. This limitation is necessary to allow the PC board and component pins to change dimensions evenly, putting minimal stresses on the component.

It is recommended to perform reflow soldering no more than twice.

For product information and a complete list of distributors, please go to our web site: wwv

www.avagotech.com





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